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NXP USA Inc. - MKL15Z128VLH4 Datasheet



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Applications of "<u>Embedded -</u> <u>Microcontrollers</u>"

Details

Product Status	Active
Core Processor	ARM® Cortex®-M0+
Core Size	32-Bit Single-Core
Speed	48MHz
Connectivity	I ² C, LINbus, SPI, TSI, UART/USART
Peripherals	Brown-out Detect/Reset, DMA, LVD, POR, PWM, WDT
Number of I/O	54
Program Memory Size	128KB (128K x 8)
Program Memory Type	FLASH
EEPROM Size	-
RAM Size	16K x 8
Voltage - Supply (Vcc/Vdd)	1.71V ~ 3.6V
Data Converters	A/D 16x16b; D/A 1x12b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 105°C (TA)
Mounting Type	Surface Mount
Package / Case	64-LQFP
Supplier Device Package	64-LQFP (10x10)
Purchase URL	https://www.e-xfl.com/product-detail/nxp-semiconductors/mkl15z128vlh4

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Address: Room A, 16/F, Full Win Commercial Centre, 573 Nathan Road, Mongkok, Hong Kong

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1 Ordering parts

1.1 Determining valid orderable parts

Valid orderable part numbers are provided on the web. To determine the orderable part numbers for this device, go to www.freescale.com and perform a part number search for the following device numbers: PKL15 and MKL15

2 Part identification

2.1 Description

Part numbers for the chip have fields that identify the specific part. You can use the values of these fields to determine the specific part you have received.

2.2 Format

Part numbers for this device have the following format:

Q KL## A FFF R T PP CC N

2.3 Fields

This table lists the possible values for each field in the part number (not all combinations are valid):

Field	Description	Values
Q	Qualification status	 M = Fully qualified, general market flow P = Prequalification
KL##	Kinetis family	• KL15
A	Key attribute	• Z = Cortex-M0+
FFF	Program flash memory size	 32 = 32 KB 64 = 64 KB 128 = 128 KB 256 = 256 KB

Table continues on the next page

3.2 Definition: Operating behavior

An *operating behavior* is a specified value or range of values for a technical characteristic that are guaranteed during operation if you meet the operating requirements and any other specified conditions.

3.2.1 Example

This is an example of an operating behavior, which is guaranteed if you meet the accompanying operating requirements:

Symbol	Description	Min.	Max.	Unit
I _{WP}	Digital I/O weak pullup/ pulldown current	10	130	μΑ

3.3 Definition: Attribute

An *attribute* is a specified value or range of values for a technical characteristic that are guaranteed, regardless of whether you meet the operating requirements.

3.3.1 Example

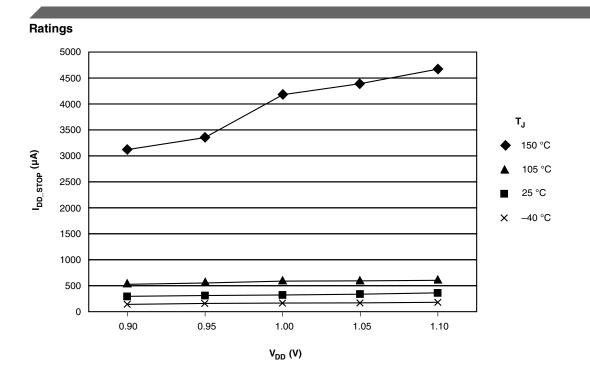
This is an example of an attribute:

Symbol	Description	Min.	Max.	Unit
CIN_D	Input capacitance: digital pins	—	7	pF

3.4 Definition: Rating

A *rating* is a minimum or maximum value of a technical characteristic that, if exceeded, may cause permanent chip failure:

- Operating ratings apply during operation of the chip.
- *Handling ratings* apply when the chip is not powered.



3.9 Typical Value Conditions

Typical values assume you meet the following conditions (or other conditions as specified):

Symbol	Description	Value	Unit
T _A	Ambient temperature	25	٦°
V _{DD}	3.3 V supply voltage	3.3	V

4 Ratings

4.1 Thermal handling ratings

Symbol	Description	Min.	Max.	Unit	Notes
T _{STG}	Storage temperature	-55	150	°C	1
T _{SDR}	Solder temperature, lead-free	_	260	°C	2

1. Determined according to JEDEC Standard JESD22-A103, High Temperature Storage Life.

2. Determined according to IPC/JEDEC Standard J-STD-020, Moisture/Reflow Sensitivity Classification for Nonhermetic Solid State Surface Mount Devices.

4.2 Moisture handling ratings

Symbol	Description	Min.	Max.	Unit	Notes
MSL	Moisture sensitivity level	_	3	_	1

1. Determined according to IPC/JEDEC Standard J-STD-020, *Moisture/Reflow Sensitivity Classification for Nonhermetic Solid State Surface Mount Devices*.

4.3 ESD handling ratings

Symbol	Description	Min.	Max.	Unit	Notes
V _{HBM}	Electrostatic discharge voltage, human body model	-2000	+2000	V	1
V _{CDM}	Electrostatic discharge voltage, charged-device model	-500	+500	V	2
I _{LAT}	Latch-up current at ambient temperature of 105°C	-100	+100	mA	

- 1. Determined according to JEDEC Standard JESD22-A114, *Electrostatic Discharge (ESD) Sensitivity Testing Human Body Model (HBM)*.
- 2. Determined according to JEDEC Standard JESD22-C101, Field-Induced Charged-Device Model Test Method for Electrostatic-Discharge-Withstand Thresholds of Microelectronic Components.

4.4 Voltage and current operating ratings

Symbol	Description	Min.	Max.	Unit
V _{DD}	Digital supply voltage	-0.3	3.8	V
I _{DD}	Digital supply current	—	120	mA
V _{DIO}	Digital pin input voltage (except RESET)	-0.3	3.6	V
V _{AIO}	Analog pins ¹ and RESET pin input voltage	-0.3	V _{DD} + 0.3	V
Ι _D	Instantaneous maximum current single pin limit (applies to all port pins)	-25	25	mA
V _{DDA}	Analog supply voltage	V _{DD} – 0.3	V _{DD} + 0.3	V

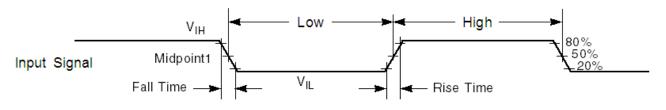
1. Analog pins are defined as pins that do not have an associated general purpose I/O port function.

5 General

General

5.1 AC electrical characteristics

Unless otherwise specified, propagation delays are measured from the 50% to the 50% point, and rise and fall times are measured at the 20% and 80% points, as shown in the following figure.



The midpoint is V_{IL} + $(V_{IH} - V_{IL})/2$.

Figure 1. Input signal measurement reference

All digital I/O switching characteristics, unless otherwise specified, assumes:

- 1. output pins
 - have $C_L=30$ pF loads,
 - are slew rate disabled, and
 - are normal drive strength

5.2 Nonswitching electrical specifications

5.2.1 Voltage and current operating requirements

Table 1. Voltage and current operating requirements

Symbol	Description	Min.	Max.	Unit	Notes
V _{DD}	Supply voltage	1.71	3.6	V	
V _{DDA}	Analog supply voltage	1.71	3.6	V	
$V_{DD} - V_{DDA}$	V _{DD} -to-V _{DDA} differential voltage	-0.1	0.1	V	
$V_{SS} - V_{SSA}$	V _{SS} -to-V _{SSA} differential voltage	-0.1	0.1	V	
V _{IH}	Input high voltage				
	• $2.7 \text{ V} \le \text{V}_{\text{DD}} \le 3.6 \text{ V}$	$0.7 \times V_{DD}$	—	V	
	• $1.7 \text{ V} \le \text{V}_{\text{DD}} \le 2.7 \text{ V}$	$0.75 \times V_{DD}$	_	V	
V _{IL}	Input low voltage				
	• $2.7 \text{ V} \le \text{V}_{\text{DD}} \le 3.6 \text{ V}$	—	$0.35 \times V_{DD}$	V	
	• $1.7 \text{ V} \le \text{V}_{\text{DD}} \le 2.7 \text{ V}$	_	$0.3 \times V_{DD}$	V	
V _{HYS}	Input hysteresis	$0.06 \times V_{DD}$	—	V	

Table continues on the next page...

Symbol	Description	Min.	Max.	Unit	Notes
I _{ICDIO}	Digital pin negative DC injection current — single pin • V _{IN} < V _{SS} -0.3V	-5	_	mA	1
I _{ICAIO}	 Analog² pin DC injection current — single pin V_{IN} < V_{SS}-0.3V (Negative current injection) V_{IN} > V_{DD}+0.3V (Positive current injection) 	-5	 +5	mA	3
I _{ICcont}	 Contiguous pin DC injection current —regional limit, includes sum of negative injection currents or sum of positive injection currents of 16 contiguous pins Negative current injection Positive current injection 	-25 —	 +25	mA	
V _{RAM}	V _{DD} voltage required to retain RAM	1.2	—	V	

Table 1. Voltage and current operating requirements (continued)

- All digital I/O pins are internally clamped to V_{SS} through a ESD protection diode. There is no diode connection to V_{DD}. If V_{IN} greater than V_{DIO_MIN} (=V_{SS}-0.3V) is observed, then there is no need to provide current limiting resistors at the pads. If this limit cannot be observed then a current limiting resistor is required. The negative DC injection current limiting resistor is calculated as R=(V_{DIO_MIN}-V_{IN})/|I_{IC}|.
- 2. Analog pins are defined as pins that do not have an associated general purpose I/O port function.
- 3. All analog pins are internally clamped to V_{SS} and V_{DD} through ESD protection diodes. If V_{IN} is greater than V_{AIO_MIN} (= V_{SS} -0.3V) and V_{IN} is less than V_{AIO_MAX} (= V_{DD} +0.3V) is observed, then there is no need to provide current limiting resistors at the pads. If these limits cannot be observed then a current limiting resistor is required. The negative DC injection current limiting resistor is calculated as R=(V_{AIO_MIN} - V_{IN})/II_{IC}I. The positive injection current limiting resistor is calculated as R=(V_{AIO_MIN} - V_{IN})/II_{IC}I. The positive injection current limiting resistor is calculated as R=(V_{IN} - V_{AIO_MAX})/II_{IC}I. Select the larger of these two calculated resistances.

5.2.2 LVD and POR operating requirements

Symbol	Description	Min.	Тур.	Max.	Unit	Notes
V _{POR}	Falling VDD POR detect voltage	0.8	1.1	1.5	V	
V _{LVDH}	Falling low-voltage detect threshold — high range (LVDV=01)	2.48	2.56	2.64	V	
	Low-voltage warning thresholds — high range					1
V _{LVW1H}	Level 1 falling (LVWV=00)	2.62	2.70	2.78	V	
V _{LVW2H}	Level 2 falling (LVWV=01)	2.72	2.80	2.88	V	
V _{LVW3H}	Level 3 falling (LVWV=10)	2.82	2.90	2.98	V	
V _{LVW4H}	Level 4 falling (LVWV=11)	2.92	3.00	3.08	V	
V _{HYSH}	Low-voltage inhibit reset/recover hysteresis — high range	_	±60	_	mV	
V _{LVDL}	Falling low-voltage detect threshold — low range (LVDV=00)	1.54	1.60	1.66	V	

Table continues on the next page...

Symbol	Description	Min.	Тур.	Max.	Unit	Notes
I _{DD_VLLS0}	Very low-leakage stop mode 0 current (SMC_STOPCTRL[PORPO] = 0) at 3.0 V		001	0.40	nA	
	at 25 °C		381 956	943 11760		
	at 50 °C	_	2370	13260		
	at 70 °C	_	4800	15700		
	at 85 °C	_	12410	23480		
	at 105 °C					
I _{DD_VLLS0}	Very low-leakage stop mode 0 current (SMC_STOPCTRL[PORPO] = 1) at 3.0 V	_	176	860		6
	at 25 °C	_	760	3577	nA	
	at 50 °C	_	2120	11660		
	at 70 °C	_	4500	18450		
	at 85 °C	_	12130	22441		
	at 105 °C					

Table 5. Power consumption operating behaviors (continued)

1. The analog supply current is the sum of the active or disabled current for each of the analog modules on the device. See each module's specification for its supply current.

- 2. MCG configured for PEE mode. CoreMark benchmark compiled using Keil 4.54 with optimization level 3, optimized for time.
- 3. MCG configured for FEI mode.
- 4. Incremental current consumption from peripheral activity is not included.
- 5. MCG configured for BLPI mode.
- 6. No brownout

Table 6. Low power mode peripheral adders — typical value

Symbol	Description		Temperature (°C)					Unit
		-40	25	50	70	85	105	
IIREFSTEN4MHz	4 MHz internal reference clock (IRC) adder. Measured by entering STOP or VLPS mode with 4 MHz IRC enabled.	56	56	56	56	56	56	μA
IREFSTEN32KHz	32 kHz internal reference clock (IRC) adder. Measured by entering STOP mode with the 32 kHz IRC enabled.	52	52	52	52	52	52	μA
IEREFSTEN4MHz	External 4MHz crystal clock adder. Measured by entering STOP or VLPS mode with the crystal enabled.	206	228	237	245	251	258	uA

Table continues on the next page ...

General

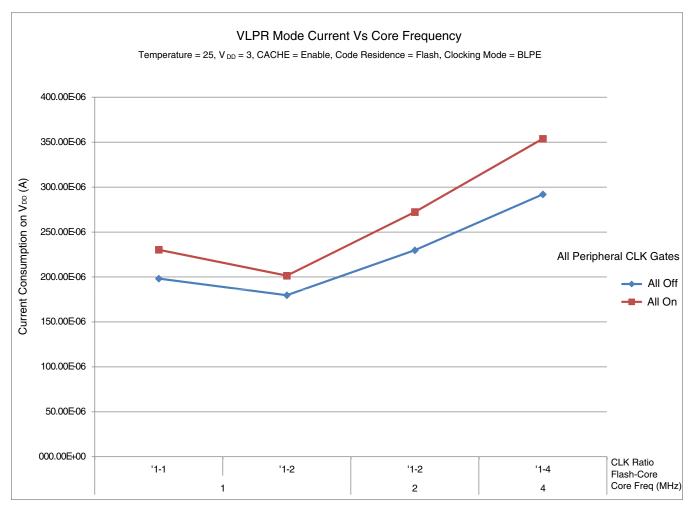


Figure 3. VLPR mode current vs. core frequency

5.2.6 EMC radiated emissions operating behaviors

Table 7. EMC radiated emissions operating behaviors for 64-pin LQFP package

Symbol	Description	Frequency band (MHz)	Тур.	Unit	Notes
V _{RE1}	Radiated emissions voltage, band 1	0.15–50	13	dBµV	1, 2
V _{RE2}	Radiated emissions voltage, band 2	50–150	15	dBµV	
V _{RE3}	Radiated emissions voltage, band 3	150–500	12	dBµV	
V _{RE4}	Radiated emissions voltage, band 4	500–1000	7	dBµV	
V_{RE_IEC}	IEC level	0.15–1000	М	—	2, 3

 Determined according to IEC Standard 61967-1, Integrated Circuits - Measurement of Electromagnetic Emissions, 150 kHz to 1 GHz Part 1: General Conditions and Definitions and IEC Standard 61967-2, Integrated Circuits - Measurement of Electromagnetic Emissions, 150 kHz to 1 GHz Part 2: Measurement of Radiated Emissions – TEM Cell and Wideband TEM Cell Method. Measurements were made while the microcontroller was running basic application code. The reported emission level is the value of the maximum measured emission, rounded up to the next whole number, from among the measured orientations in each frequency range.

5.4.2 Thermal attributes

Board type	Symbol	Description	80 LQFP	64 LQFP	48 QFN	32 QFN	Unit	Notes
Single-layer (1S)	R _{θJA}	Thermal resistance, junction to ambient (natural convection)	70	71	84	92	°C/W	1
Four-layer (2s2p)	R _{θJA}	Thermal resistance, junction to ambient (natural convection)	53	52	28	33	°C/W	
Single-layer (1S)	R _{θJMA}	Thermal resistance, junction to ambient (200 ft./min. air speed)	_	59	69	75	°C/W	
Four-layer (2s2p)	R _{θJMA}	Thermal resistance, junction to ambient (200 ft./min. air speed)	_	46	22	27	°C/W	
_	R _{θJB}	Thermal resistance, junction to board	34	34	10	12	°C/W	2
_	R _{θJC}	Thermal resistance, junction to case	15	20	2.0	1.8	°C/W	3
	Ψ_{JT}	Thermal characterization parameter, junction to package top outside center (natural convection)	0.6	5	5.0	8	°C/W	4

Table 10. Thermal attributes

- 1. Determined according to JEDEC Standard JESD51-2, Integrated Circuits Thermal Test Method Environmental Conditions —Natural Convection (Still Air), or EIA/JEDEC Standard JESD51-6, Integrated Circuit Thermal Test Method Environmental Conditions—Forced Convection (Moving Air).
- 2. Determined according to JEDEC Standard JESD51-8, Integrated Circuit Thermal Test Method Environmental Conditions —Junction-to-Board.
- 3. Determined according to Method 1012.1 of MIL-STD 883, *Test Method Standard, Microcircuits*, with the cold plate temperature used for the case temperature. The value includes the thermal resistance of the interface material between the top of the package and the cold plate.
- 4. Determined according to JEDEC Standard JESD51-2, Integrated Circuits Thermal Test Method Environmental Conditions —Natural Convection (Still Air).

6 Peripheral operating requirements and behaviors

6.1 Core modules

6.1.1 SWD Electricals

Table 11. SWD full voltage range electricals

Symbol	Description	Min.	Max.	Unit
	Operating voltage	1.71	3.6	V

Table continues on the next page...

Peripheral operating requirements and behaviors

Symbol	Description		Min.	Тур.	Max.	Unit	Notes
f _{dco_t_DMX32}	DCO output frequency	Low range (DRS = 00) 732 × f _{fll_ref}	—	23.99	-	MHz	5, 6
		Mid range (DRS = 01) 1464 $\times f_{fll ref}$	_	47.97	-	MHz	-
J _{cyc_fll}	FLL period jitter • f _{VCO} = 48 M	_	_	180	-	ps	7
t _{fll_acquire}		ncy acquisition time	_	_	1	ms	8
		PL	L				
f _{vco}	VCO operating fre	quency	48.0	_	100	MHz	
I _{pll}	PLL operating cur PLL at 96 M MHz, VDIV	rent Hz ($f_{osc_{hi_1}} = 8 \text{ MHz}, f_{pll_{ref}} = 2$ multiplier = 48)	_	1060	-	μΑ	9
I _{pll}	PLL operating cur PLL at 48 M MHz, VDIV	rent Hz ($f_{osc_{hi_1}} = 8 \text{ MHz}, f_{pll_{ref}} = 2$ multiplier = 24)	_	600	-	μΑ	9
f _{pll_ref}	PLL reference free	quency range	2.0	—	4.0	MHz	
J _{cyc_pll}	PLL period jitter (F • f _{vco} = 48 MH • f _{vco} = 100 M	lz	_	120 50	_	ps ps	10
J _{acc_pll}	PLL accumulated • f _{vco} = 48 MH	jitter over 1µs (RMS) Iz		1350	_	ps	10
	• f _{vco} = 100 M	Hz	_	600	_	ps	
D _{lock}	Lock entry frequer	ncy tolerance	± 1.49	—	± 2.98	%	
D _{unl}	Lock exit frequence	y tolerance	± 4.47	—	± 5.97	%	
t _{pll_lock}	Lock detector dete	ection time	_	—	150 × 10 ⁻⁶ + 1075(1/ f _{pll_ref})	S	11

Table 12. MCG specifications (continued)

- 1. This parameter is measured with the internal reference (slow clock) being used as a reference to the FLL (FEI clock mode).
- 2. The deviation is relative to the factory trimmed frequency at nominal V_{DD} and 25 °C, $f_{ints_{-}ft}$.
- 3. These typical values listed are with the slow internal reference clock (FEI) using factory trim and DMX32 = 0.
- The resulting system clock frequencies must not exceed their maximum specified values. The DCO frequency deviation (Δf_{dco t}) over voltage and temperature must be considered.
- 5. These typical values listed are with the slow internal reference clock (FEI) using factory trim and DMX32 = 1.
- 6. The resulting clock frequency must not exceed the maximum specified clock frequency of the device.
- 7. This specification is based on standard deviation (RMS) of period or frequency.
- 8. This specification applies to any time the FLL reference source or reference divider is changed, trim value is changed, DMX32 bit is changed, DRS bits are changed, or changing from FLL disabled (BLPE, BLPI) to FLL enabled (FEI, FEE, FBE, FBI). If a crystal/resonator is being used as the reference, this specification assumes it is already running.

9. Excludes any oscillator currents that are also consuming power while PLL is in operation.

- 10. This specification was obtained using a Freescale developed PCB. PLL jitter is dependent on the noise characteristics of each PCB and results will vary.
- 11. This specification applies to any time the PLL VCO divider or reference divider is changed, or changing from PLL disabled (BLPE, BLPI) to PLL enabled (PBE, PEE). If a crystal/resonator is being used as the reference, this specification assumes it is already running.

Peripheral operating requirements and behaviors

6.4.1.2 Flash timing specifications — commands Table 16. Flash command timing specifications

Symbol	Description	Min.	Тур.	Max.	Unit	Notes
t _{rd1sec1k}	Read 1s Section execution time (flash sector)	_	—	60	μs	1
t _{pgmchk}	Program Check execution time	_	—	45	μs	1
t _{rdrsrc}	Read Resource execution time	_	—	30	μs	1
t _{pgm4}	Program Longword execution time	_	65	145	μs	
t _{ersscr}	Erase Flash Sector execution time	_	14	114	ms	2
t _{rd1all}	Read 1s All Blocks execution time	_	—	1.8	ms	
t _{rdonce}	Read Once execution time	_	—	25	μs	1
t _{pgmonce}	Program Once execution time	_	65	_	μs	
t _{ersall}	Erase All Blocks execution time	_	62	500	ms	2
t _{vfykey}	Verify Backdoor Access Key execution time	_	—	30	μs	1

1. Assumes 25MHz flash clock frequency.

2. Maximum times for erase parameters based on expectations at cycling end-of-life.

6.4.1.3 Flash high voltage current behaviors Table 17. Flash high voltage current behaviors

Symbol	Description	Min.	Тур.	Max.	Unit
I _{DD_PGM}	Average current adder during high voltage flash programming operation	—	2.5	6.0	mA
I _{DD_ERS}	Average current adder during high voltage flash erase operation		1.5	4.0	mA

6.4.1.4 Reliability specifications

Table 18. NVM reliability specifications

Symbol	Description	Min.	Typ. ¹	Max.	Unit	Notes
	Progra	m Flash	_			
t _{nvmretp10k}	Data retention after up to 10 K cycles	5	50	—	years	
t _{nvmretp1k}	Data retention after up to 1 K cycles	20	100	—	years	
n _{nvmcycp}	Cycling endurance	10 K	50 K		cycles	2

 Typical data retention values are based on measured response accelerated at high temperature and derated to a constant 25°C use profile. Engineering Bulletin EB618 does not apply to this technology. Typical endurance defined in Engineering Bulletin EB619.

2. Cycling endurance represents number of program/erase cycles at -40°C \leq T_i \leq 125°C.

6.5 Security and integrity modules

There are no specifications necessary for the device's security and integrity modules.

6.6 Analog

6.6.1 ADC electrical specifications

The 16-bit accuracy specifications listed in Table 19 and Table 20 are achievable on the differential pins ADCx_DP0, ADCx_DM0.

All other ADC channels meet the 13-bit differential/12-bit single-ended accuracy specifications.

Symbol	Description	Conditions	Min.	Typ. ¹	Max.	Unit	Notes
V _{DDA}	Supply voltage	Absolute	1.71	_	3.6	V	
ΔV_{DDA}	Supply voltage	Delta to V _{DD} (V _{DD} -V _{DDA})	-100	0	+100	mV	2
ΔV_{SSA}	Ground voltage	Delta to V _{SS} (V _{SS} - V _{SSA})	-100	0	+100	mV	2
V _{REFH}	ADC reference voltage high		1.13	V _{DDA}	V _{DDA}	V	3
V _{REFL}	V _{REFL} ADC reference voltage low		V _{SSA}	V _{SSA}	V _{SSA}	V	3
V _{ADIN} Input voltage			V _{REFL}	_	V _{REFH}	V	
C _{ADIN}	Input capacitance	16-bit mode	—	8	10	pF	
		• 8-/10-/12-bit modes	—	4	5		
R _{ADIN}	Input resistance		—	2	5	kΩ	
R _{AS}	Analog source resistance	13-/12-bit modes f _{ADCK} < 4 MHz	_	_	5	kΩ	4
f _{ADCK}	ADC conversion clock frequency	≤ 1312-bit mode	1.0		18.0	MHz	5
f _{ADCK}	ADC conversion clock frequency	16-bit mode	2.0	_	12.0	MHz	5
C _{rate}	ADC conversion rate	≤ 1312 bit modes No ADC hardware averaging Continuous conversions enabled, subsequent conversion time	20.000		818.330	Ksps	6

6.6.1.1 16-bit ADC operating conditions Table 19. 16-bit ADC operating conditions

Table continues on the next page...

Peripheral operating requirements and behaviors

Symbol	Description	Conditions	Min.	Typ. ¹	Max.	Unit	Notes
C _{rate}	ADC conversion rate	16-bit mode No ADC hardware averaging	37.037	_	461.467	Ksps	6
		Continuous conversions enabled, subsequent conversion time					

 Table 19.
 16-bit ADC operating conditions (continued)

- 1. Typical values assume V_{DDA} = 3.0 V, Temp = 25 °C, f_{ADCK} = 1.0 MHz unless otherwise stated. Typical values are for reference only and are not tested in production.
- 2. DC potential difference.
- 3. For packages without dedicated VREFH and VREFL pins, V_{REFH} is internally tied to V_{DDA} , and V_{REFL} is internally tied to V_{SSA} .
- 4. This resistance is external to MCU. The analog source resistance must be kept as low as possible to achieve the best results. The results in this data sheet were derived from a system which has < 8 Ω analog source resistance. The R_{AS}/C_{AS} time constant should be kept to < 1ns.</p>
- 5. To use the maximum ADC conversion clock frequency, the ADHSC bit must be set and the ADLPC bit must be clear.
- 6. For guidelines and examples of conversion rate calculation, download the ADC calculator tool

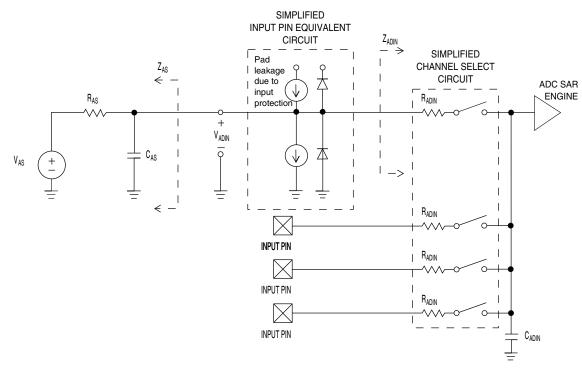


Figure 6. ADC input impedance equivalency diagram

6.6.1.2 16-bit ADC electrical characteristics Table 20. 16-bit ADC characteristics (V_{REFH} = V_{DDA}, V_{REFL} = V_{SSA})

Symbol	Description	Conditions ¹	Min.	Typ. ²	Max.	Unit	Notes
I _{DDA_ADC}	Supply current		0.215	_	1.7	mA	3

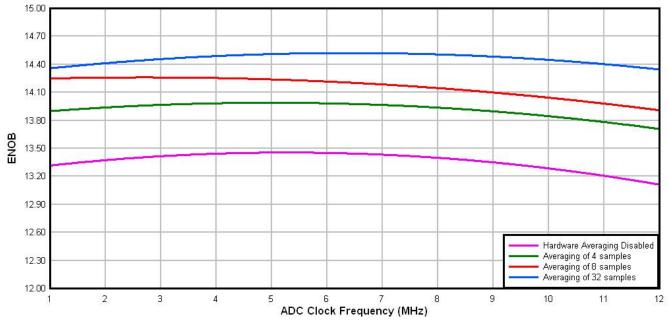
Table continues on the next page...

Symbol	Description	Conditions ¹	Min.	Typ. ²	Max.	Unit	Notes
E _{IL}	Input leakage error			I _{In} × R _{AS}		mV	I _{In} = leakage current (refer to the MCU's voltage and current operating ratings)
	Temp sensor slope	Across the full temperature range of the device	_	1.715	_	mV/°C	
V _{TEMP25}	Temp sensor voltage	25 °C	_	719	—	mV	

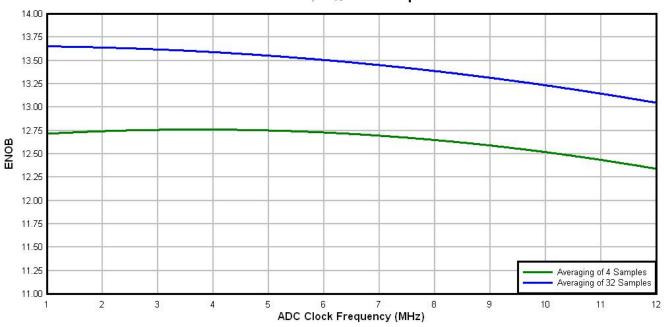
Table 20. 16-bit ADC characteristics ($V_{REFH} = V_{DDA}$, $V_{REFL} = V_{SSA}$) (continued)

- 1. All accuracy numbers assume the ADC is calibrated with V_{REFH} = V_{DDA}
- Typical values assume V_{DDA} = 3.0 V, Temp = 25°C, f_{ADCK} = 2.0 MHz unless otherwise stated. Typical values are for reference only and are not tested in production.
- The ADC supply current depends on the ADC conversion clock speed, conversion rate and the ADLPC bit (low power). For lowest power operation the ADLPC bit must be set, the HSC bit must be clear with 1 MHz ADC conversion clock speed.
- 4. 1 LSB = $(V_{REFH} V_{REFL})/2^N$
- 5. ADC conversion clock < 16 MHz, Max hardware averaging (AVGE = %1, AVGS = %11)
- 6. Input data is 100 Hz sine wave. ADC conversion clock < 12 MHz.
- 7. Input data is 1 kHz sine wave. ADC conversion clock < 12 MHz.









Typical ADC 16-bit Single-Ended ENOB vs ADC Clock 100Hz, 90% FS Sine Input

Figure 8. Typical ENOB vs. ADC_CLK for 16-bit single-ended mode

6.6.2 CMP and 6-bit DAC electrical specifications Table 21. Comparator and 6-bit DAC electrical specifications

Symbol	Description	Min.	Тур.	Max.	Unit
V _{DD}	Supply voltage	1.71		3.6	V
I _{DDHS}	Supply current, high-speed mode (EN = 1, PMODE = 1)	_	_	200	μA
I _{DDLS}	Supply current, low-speed mode (EN = 1, PMODE = 0)	_	_	20	μA
V _{AIN}	Analog input voltage	V _{SS}	_	V _{DD}	V
V _{AIO}	Analog input offset voltage	—	_	20	mV
V _H	Analog comparator hysteresis ¹				
	• CR0[HYSTCTR] = 00	_	5	_	mV
	• CR0[HYSTCTR] = 01	_	10	_	mV
	• CR0[HYSTCTR] = 10	_	20	_	mV
	• CR0[HYSTCTR] = 11	—	30	_	mV
V _{CMPOh}	Output high	V _{DD} – 0.5			V
V _{CMPOI}	Output low	_	_	0.5	V
t _{DHS}	Propagation delay, high-speed mode (EN = 1, PMODE = 1)	20	50	200	ns
t _{DLS}	Propagation delay, low-speed mode (EN = 1, PMODE = 0)	80	250	600	ns

Table continues on the next page ...

Peripheral operating requirements and behaviors

Table 21. Comparator and 6-bit DAC electrical specifications (continued	Table 21.	Comparator and	d 6-bit DAC electrical s	specifications	(continued)
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Symbol	Description	Min.	Тур.	Max.	Unit
	Analog comparator initialization delay ²	—	—	40	μs
I _{DAC6b}	6-bit DAC current adder (enabled)	_	7	—	μA
INL	6-bit DAC integral non-linearity	-0.5	—	0.5	LSB ³
DNL	6-bit DAC differential non-linearity	-0.3	—	0.3	LSB

1. Typical hysteresis is measured with input voltage range limited to 0.7 to V_{DD} – 0.7 V.

- 2. Comparator initialization delay is defined as the time between software writes to change control inputs (writes to DACEN,
- VRSEL, PSEL, MSEL, VOSEL) and the comparator output settling to a stable level.
- 3. 1 LSB = V_{reference}/64

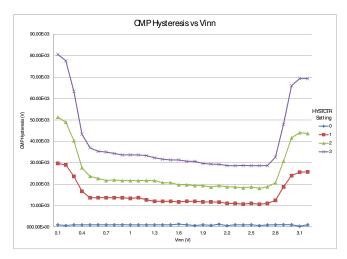


Figure 9. Typical hysteresis vs. Vin level (V_{DD} = 3.3 V, PMODE = 0)

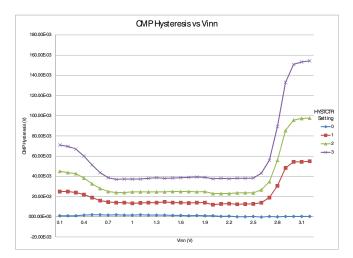


Figure 10. Typical hysteresis vs. Vin level (V_{DD} = 3.3 V, PMODE = 1)

6.6.3 12-bit DAC electrical characteristics

6.6.3.1 12-bit DAC operating requirements Table 22. 12-bit DAC operating requirements

Symbol	Desciption	Min.	Max.	Unit	Notes
V _{DDA}	Supply voltage	1.71	3.6	V	
V _{DACR}	Reference voltage	1.13	3.6	V	1
T _A	Temperature		emperature he device	°C	
CL	Output load capacitance	_	100	pF	2
١L	Output load current	— 1		mA	

1. The DAC reference can be selected to be V_{DDA} or the voltage output of the VREF module (VREF_OUT)

2. A small load capacitance (47 pF) can improve the bandwidth performance of the DAC

6.6.3.2 12-bit DAC operating behaviors Table 23. 12-bit DAC operating behaviors

Symbol	Description	Min.	Тур.	Max.	Unit	Notes
I _{DDA_DACL}	Supply current — low-power mode	—	—	250	μΑ	
I _{DDA_DACH} P	Supply current — high-speed mode	_	_	900	μΑ	
t _{DACLP}	Full-scale settling time (0x080 to 0xF7F) — low-power mode		100	200	μs	1
t _{DACHP}	Full-scale settling time (0x080 to 0xF7F) — high-power mode	_	15	30	μs	1
t _{CCDACLP}	Code-to-code settling time (0xBF8 to 0xC08) — low-power mode and high-speed mode	_	0.7	1	μs	1
V _{dacoutl}	DAC output voltage range low — high-speed mode, no load, DAC set to 0x000	_	—	100	mV	
V _{dacouth}	DAC output voltage range high — high- speed mode, no load, DAC set to 0xFFF	V _{DACR} -100	—	V _{DACR}	mV	
INL	Integral non-linearity error — high speed mode	_	—	±8	LSB	2
DNL	Differential non-linearity error — V _{DACR} > 2 V	—	—	±1	LSB	3
DNL	Differential non-linearity error — V _{DACR} = VREF_OUT	—	—	±1	LSB	4
VOFFSET	Offset error	_	±0.4	±0.8	%FSR	5
E _G	Gain error	—	±0.1	±0.6	%FSR	5
PSRR	Power supply rejection ratio, $V_{DDA} \ge 2.4 \text{ V}$	60	-	90	dB	
T _{CO}	Temperature coefficient offset voltage	—	3.7	—	μV/C	6
T _{GE}	Temperature coefficient gain error	—	0.000421	—	%FSR/C	
Rop	Output resistance load = $3 \text{ k}\Omega$	—	—	250	Ω	

Table continues on the next page ...

80	64	48	32	Pin Name	Default	ALT0	ALT1	ALT2	ALT3	ALT4	ALT5	ALT6	ALT7
LQFP	LQFP	QFN	QFN	1 III Hullio	Boldan								
62	50	38	26	PTC5/ LLWU_P9	DISABLED		PTC5/ LLWU_P9	SPI0_SCK	LPTMR0_ ALT2			CMP0_OUT	
63	51	39	27	PTC6/ LLWU_P10	CMP0_IN0	CMP0_IN0	PTC6/ LLWU_P10	SPI0_MOSI	EXTRG_IN		SPI0_MISO		
64	52	40	28	PTC7	CMP0_IN1	CMP0_IN1	PTC7	SPI0_MISO			SPI0_MOSI		
65	53	-	_	PTC8	CMP0_IN2	CMP0_IN2	PTC8	I2C0_SCL	TPM0_CH4				
66	54	-	_	PTC9	CMP0_IN3	CMP0_IN3	PTC9	I2C0_SDA	TPM0_CH5				
67	55	-	-	PTC10	DISABLED		PTC10	I2C1_SCL					
68	56	_	_	PTC11	DISABLED		PTC11	I2C1_SDA					
69	_	_	_	PTC12	DISABLED		PTC12			TPM_CLKIN0			
70	_	-	_	PTC13	DISABLED		PTC13			TPM_CLKIN1			
71	_	-	_	PTC16	DISABLED		PTC16						
72	_	-	_	PTC17	DISABLED		PTC17						
73	57	41	_	PTD0	DISABLED		PTD0	SPI0_PCS0		TPM0_CH0			
74	58	42	_	PTD1	ADC0_SE5b	ADC0_SE5b	PTD1	SPI0_SCK		TPM0_CH1			
75	59	43	_	PTD2	DISABLED		PTD2	SPI0_MOSI	UART2_RX	TPM0_CH2	SPI0_MISO		
76	60	44	_	PTD3	DISABLED		PTD3	SPI0_MISO	UART2_TX	TPM0_CH3	SPI0_MOSI		
77	61	45	29	PTD4/ LLWU_P14	DISABLED		PTD4/ LLWU_P14	SPI1_PCS0	UART2_RX	TPM0_CH4			
78	62	46	30	PTD5	ADC0_SE6b	ADC0_SE6b	PTD5	SPI1_SCK	UART2_TX	TPM0_CH5			
79	63	47	31	PTD6/ LLWU_P15	ADC0_SE7b	ADC0_SE7b	PTD6/ LLWU_P15	SPI1_MOSI	UART0_RX		SPI1_MISO		
80	64	48	32	PTD7	DISABLED		PTD7	SPI1_MISO	UART0_TX		SPI1_MOSI		

8.2 KL15 Pinouts

The below figures show the pinout diagrams for the devices supported by this document. Many signals may be multiplexed onto a single pin. To determine what signals can be used on which pin, see the previous section.

Pinout

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